IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Young-pil Kim et al. Serial No.: To Be Assigned Filed: Concurrently Herewith

For: Semiconductor Device Test Patterns and Related Methods for Precisely

Measuring Leakage Currents in Semiconductor Cell Transistors

Date: March 9, 2004

Mail Stop Patent Application Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)

Sir:

Attached is a list of documents on Form PTO-1449, together with a copy of any listed foreign patent document and/or non-patent literature. A copy of any listed U.S. patent and/or U.S. patent application publication is not provided herewith in accordance with the waiver by the U.S. Patent and Trademark Office of requirements under 37 C.F.R. § 1.98(a)(2)(i) for all U.S. national patent applications filed after June 30, 2003 and for all international applications that have entered the national stage under 35 USC § 371 after June 30, 2003.

It is requested that these documents be considered by the Examiner and officially made of record in accordance with the provisions of 37 C.F.R. § 1.56 and Section 609 of the MPEP.

No fee is believed due. However, the Commissioner is hereby authorized to charge any deficiency or credit any overpayment to Deposit Account No. 50-0220.

Respectfully submitted,

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Michele P. McMahan

Substitute form 1449A/PTO	C	Complete if Known		
	Application Number	To Be Assigned		
INFORMATION DISCLOSURE	Filing Date	Concurrently Herewith		
STATEMENT BY APPLICANT	First Named Inventor	Young-pil Kim et al.		
	Group Art Unit	Unknown		
(use as many sheets as necessary)	Examiner Name	Unknown		
Sheet 1 of 1	Attorney Docket Number	5649-1276		

U.S. PATENTS AND PATENT PUBLICATIONS						
Examiner Initials*	Cite No.			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited	
	miliais		Number	Kind Code (if known)	- Document	Document MM-DD-YYYY
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FOREIGN PATENT DOCUMENTS							
Examiner Cite		Foreign Patent Document		Ocument	Name of Patentee or Applicant of Cited	Date of Publication	Т
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		OTHER NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T
	1	Young Pil Kim et al., "Reliability Degradation of High Density DRAM Cell Transistor Junction Leakage Current Induced by Band-to-Defect tunneling Under the Off-State Bias-Temperature Stress," <u>IEEE</u> , 2001	
	2	K. Saino et al., "Impact of Gate-Induced Drain Leakage Current on the Tail Distribution of DRAM Data Retention Time," IEEE, 2000	

Examiner Signature	Date Considered	